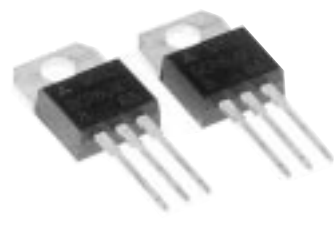


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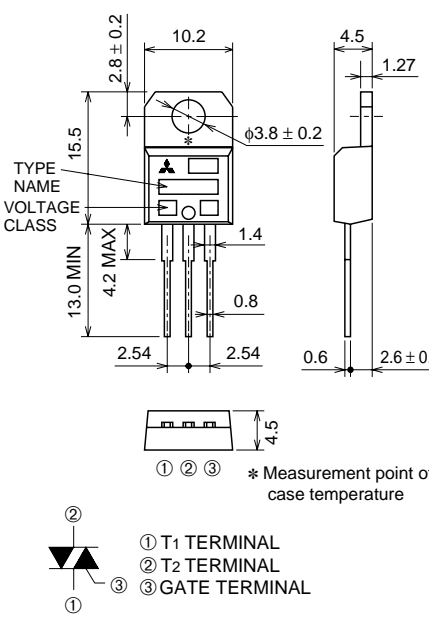
MEDIUM POWER USE
INSULATED TYPE, GLASS PASSIVATION TYPE

BCR8UM



- IT (RMS) 8A
- VDRM 400V/600V
- IFGT I, IRGT I, IRGT III 15mA
- V_{iso} 1500V

OUTLINE DRAWING Dimensions in mm



TYPE NAME
VOLTAGE CLASS

① ② ③ * Measurement point of case temperature

① T1 TERMINAL
② T2 TERMINAL
③ GATE TERMINAL

TO-220

APPLICATION

Light dimmer

MAXIMUM RATINGS

Symbol	Parameter	Voltage class		Unit
		8	12	
VDRM	Repetitive peak off-state voltage*1	400	600	V
VDSM	Non-repetitive peak off-state voltage*1	500	720	V

Symbol	Parameter	Conditions	Ratings	Unit
IT (RMS)	RMS on-state current	Commercial frequency, sine full wave 360° conduction, T _c =94°C*3	8	A
ITSM	Surge on-state current	60Hz sinewave 1 full cycle, peak value, non-repetitive	80	A
I ² _t	I ² _t for fusing	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	26	A ² s
PGM	Peak gate power dissipation		5	W
PG (AV)	Average gate power dissipation		0.5	W
VGM	Peak gate voltage		10	V
IGM	Peak gate current		2	A
T _j	Junction temperature		-40 ~ +125	°C
T _{stg}	Storage temperature		-40 ~ +125	°C
—	Weight	Typical value	2.3	g
V _{iso}	Isolation voltage	T _a =25°C, AC 1 minute, T1 · T2 · G terminal to case	1500	V

*1. Gate open.

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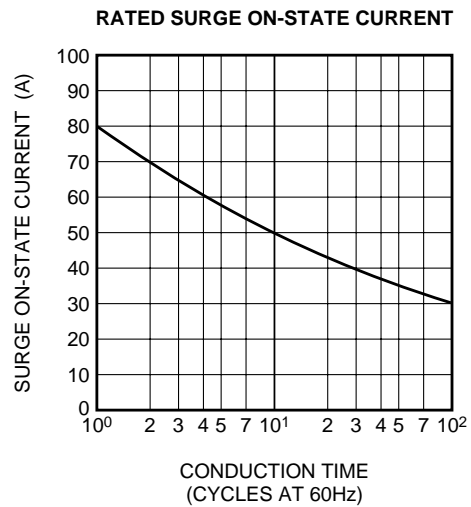
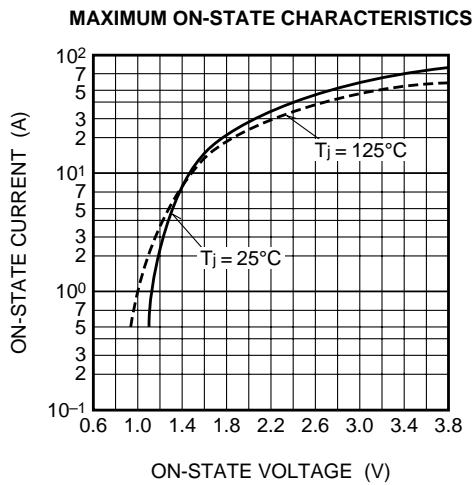
MEDIUM POWER USE
INSULATED TYPE, GLASS PASSIVATION TYPE

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit	
			Min.	Typ.	Max.		
IDRM	Repetitive peak off-state current	$T_j=125^{\circ}\text{C}$, V_{DRM} applied	—	—	2.0	mA	
VTM	On-state voltage	$T_c=25^{\circ}\text{C}$, $I_{\text{TM}}=12\text{A}$, Instantaneous measurement	—	—	1.5	V	
VFGT I	Gate trigger voltage *2	$T_j=25^{\circ}\text{C}$, $V_D=6\text{V}$, $R_L=6\Omega$, $R_G=330\Omega$	I	—	—	1.5	V
VRGT I			II	—	—	1.5	V
VRGT III			III	—	—	1.5	V
IFGT I	Gate trigger current *2	$T_j=25^{\circ}\text{C}$, $V_D=6\text{V}$, $R_L=6\Omega$, $R_G=330\Omega$	I	—	—	15	mA
IRGT I			II	—	—	15	mA
IRGT III			III	—	—	15	mA
VGD	Gate non-trigger voltage	$T_j=125^{\circ}\text{C}$, $V_D=1/2V_{\text{DRM}}$	0.2	—	—	V	
$R_{\text{th (j-c)}}$	Thermal resistance	Junction to case *3 *4	—	—	3.0	$^{\circ}\text{C/W}$	

*2. Measurement using the gate trigger characteristics measurement circuit.
 *3. Case temperature is measured at the T2 terminal 1.5mm away from the molded case.
 *4. The contact thermal resistance $R_{\text{th (c-f)}}$ in case of greasing is 1.0°C/W .

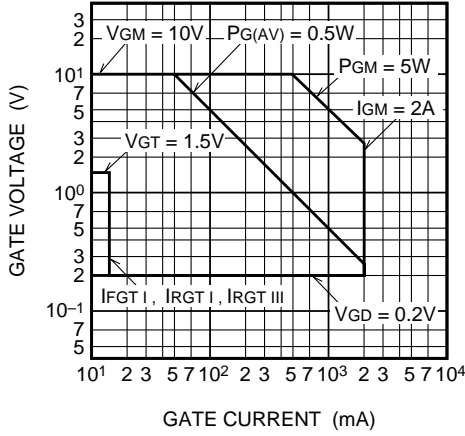
PERFORMANCE CURVES



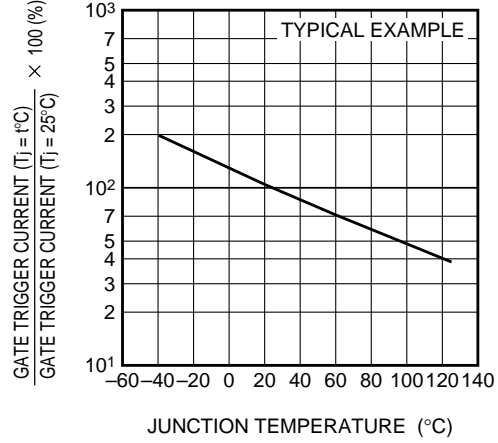
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MEDIUM POWER USE
INSULATED TYPE, GLASS PASSIVATION TYPE

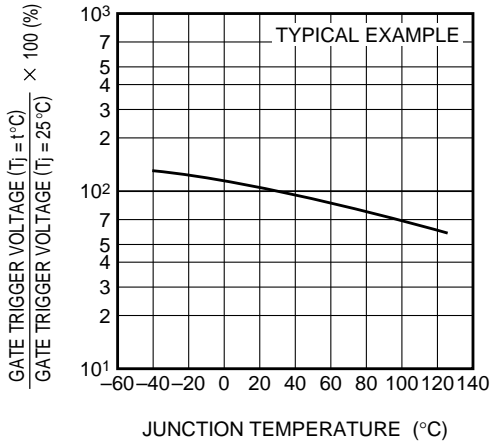
GATE CHARACTERISTICS



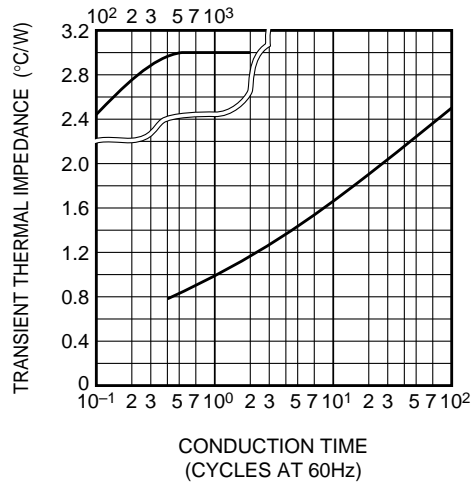
GATE TRIGGER CURRENT VS. JUNCTION TEMPERATURE



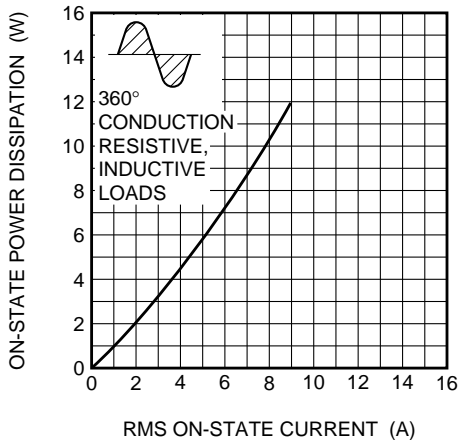
GATE TRIGGER VOLTAGE VS. JUNCTION TEMPERATURE



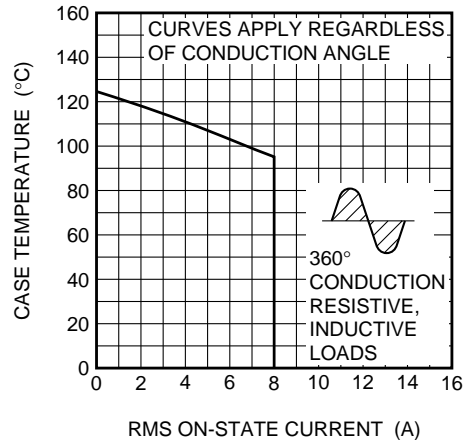
MAXIMUM TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO CASE)



MAXIMUM ON-STATE POWER DISSIPATION



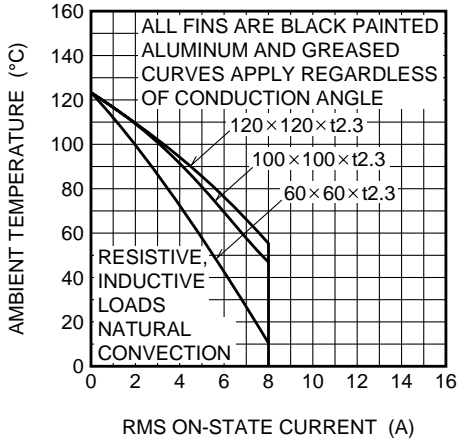
ALLOWABLE CASE TEMPERATURE VS. RMS ON-STATE CURRENT



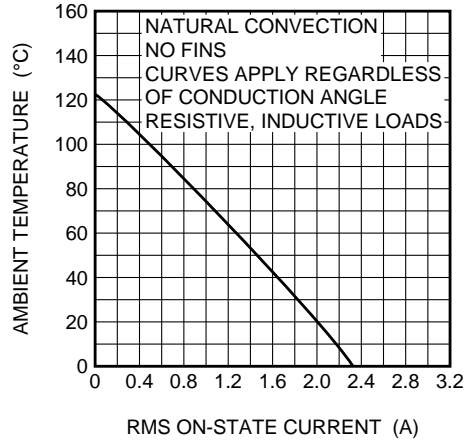
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MEDIUM POWER USE
INSULATED TYPE, GLASS PASSIVATION TYPE

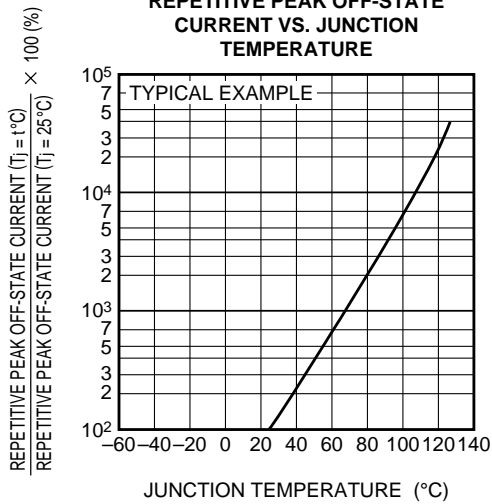
ALLOWABLE AMBIENT TEMPERATURE VS. RMS ON-STATE CURRENT



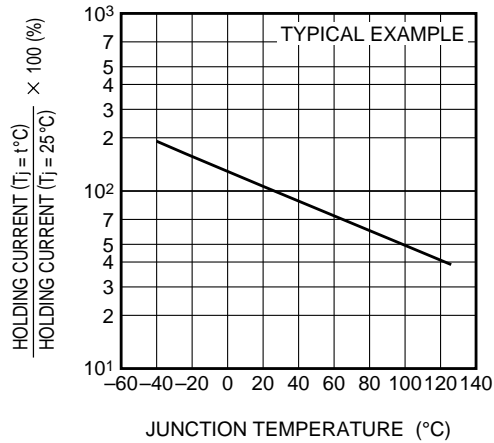
ALLOWABLE AMBIENT TEMPERATURE VS. RMS ON-STATE CURRENT



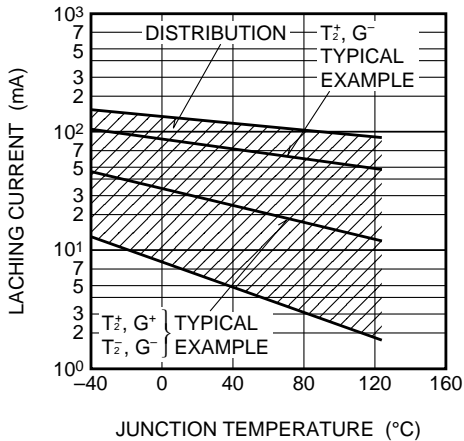
REPETITIVE PEAK OFF-STATE CURRENT VS. JUNCTION TEMPERATURE



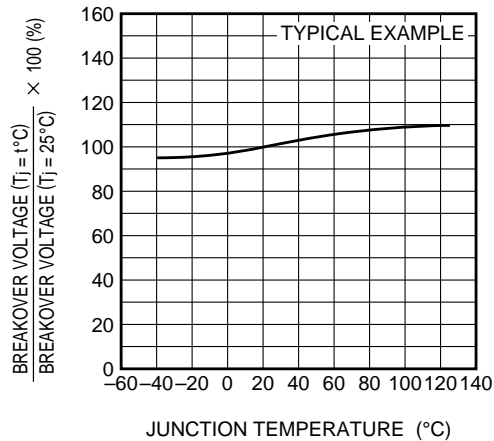
HOLDING CURRENT VS. JUNCTION TEMPERATURE



LACHING CURRENT VS. JUNCTION TEMPERATURE

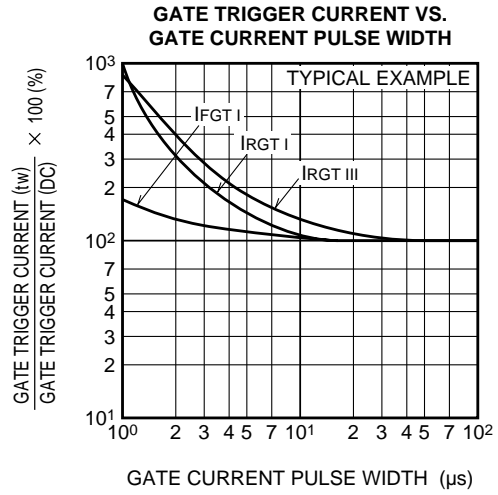
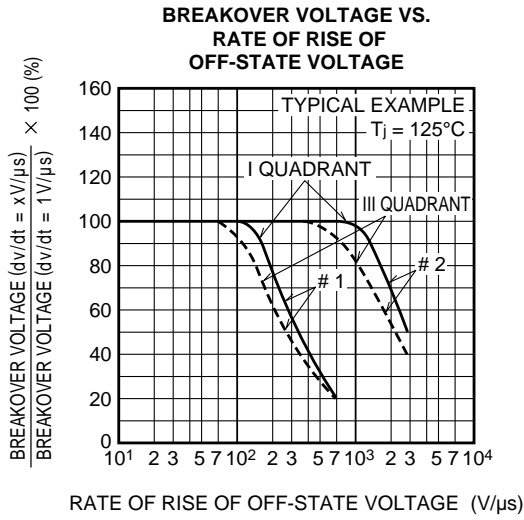


BREAKOVER VOLTAGE VS. JUNCTION TEMPERATURE



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MEDIUM POWER USE
INSULATED TYPE, GLASS PASSIVATION TYPE



GATE TRIGGER CHARACTERISTICS TEST CIRCUITS

